

CMKT5078 NPN/PNP
CMKT5087 PNP/PNP
CMKT5088 NPN/NPN

**SURFACE MOUNT
DUAL SILICON TRANSISTORS**

ULTRAmini™



SOT-363 CASE



www.centrasemi.com

DESCRIPTION:

The Central Semiconductor CMKT5078 (one each NPN and PNP complementary), CMKT5087 (two single PNP), and CMKT5088 (two single NPN) are combinations of transistors in a space saving SOT-363 ULTRAmini™ package, designed for applications requiring high gain and low noise.

CMKT5078 MARKING CODE: K78

CMKT5087 MARKING CODE: K87

CMKT5088 MARKING CODE: K88

FEATURES:

- ULTRAmini™ space saving package
- Two NPN (5088) or Two PNP (5087) Transistors in a single package
- One NPN (5088) and one PNP (5087) complementary Transistor in a single package

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage
Collector-Emitter Voltage
Emitter-Base Voltage
Continuous Collector Current
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL	NPN	PNP	UNITS
V_{CB0}	35	50	V
V_{CEO}	30	50	V
V_{EBO}	4.5	3.0	V
I_C	50		mA
P_D	350		mW
T_J, T_{stg}	-65 to +150		$^\circ\text{C}$
Θ_{JA}	357		$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS PER TRANSISTOR: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	NPN		PNP		UNITS
		MIN	MAX	MIN	MAX	
I_{CBO}	$V_{CB}=10\text{V}$	-	-	-	10	nA
I_{CBO}	$V_{CB}=35\text{V}$	-	-	-	50	nA
I_{CBO}	$V_{CB}=20\text{V}$	-	50	-	-	nA
I_{EBO}	$V_{EB}=3.0\text{V}$	-	50	-	-	nA
BV_{CBO}	$I_C=100\mu\text{A}$	35	-	50	-	V
BV_{CEO}	$I_C=1.0\text{mA}$	30	-	50	-	V
BV_{EBO}	$I_E=100\mu\text{A}$	4.5	-	3.0	-	V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$	-	0.50	-	0.30	V
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$	-	0.80	-	0.85	V
h_{FE}	$V_{CE}=5.0\text{V}, I_C=0.1\text{mA}$	300	900	250	800	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}$	350	-	250	-	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=10\text{mA}$	300	-	250	-	
f_T	$V_{CE}=5.0\text{V}, I_C=500\mu\text{A}, f=20\text{MHz}$	50	-	40	-	MHz
C_{ob}	$V_{CB}=5.0\text{V}, I_E=0, f=1.0\text{MHz}$	-	4.0	-	4.0	pF
C_{ib}	$V_{BE}=0.5\text{V}, I_C=0, f=1.0\text{MHz}$	-	15	-	-	pF
h_{fe}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$	350	1400	250	900	
NF	$V_{CE}=5.0\text{V}, I_C=100\mu\text{A}, R_S=10\text{k}\Omega, f=10\text{Hz to } 15.7\text{kHz}$	-	3.0	-	2.0	dB

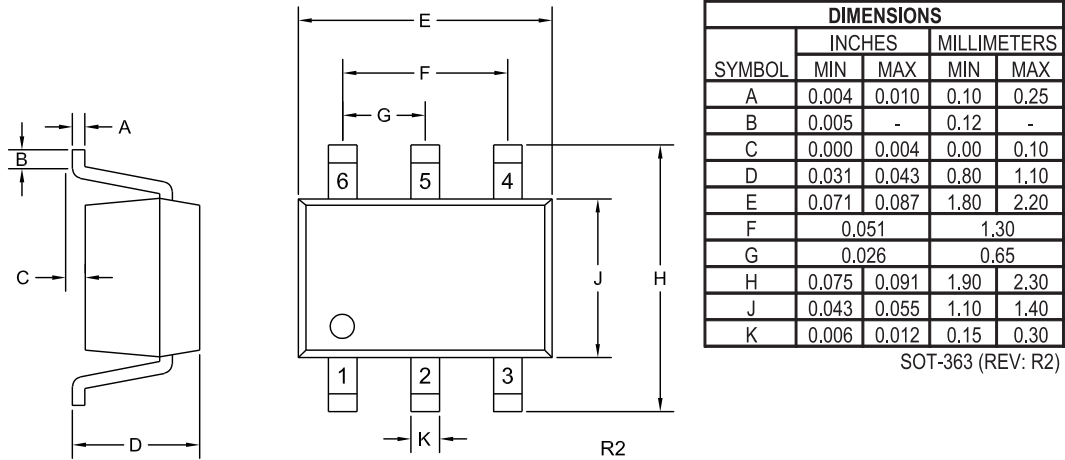
R4 (13-January 2010)

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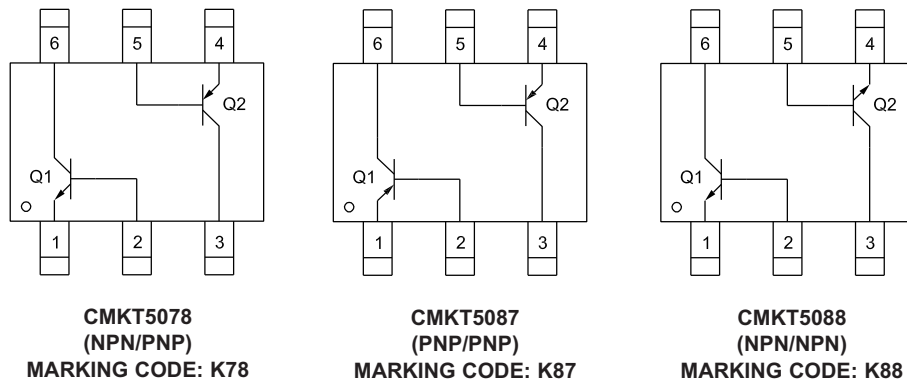
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SOT-363 CASE - MECHANICAL OUTLINE



PIN CONFIGURATIONS



LEAD CODES:

- 1) Emitter Q1
- 2) Base Q1
- 3) Collector Q1
- 4) Emitter Q2
- 5) Base Q2
- 6) Collector Q2

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